Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Glass and metal **Overall Length:** 0.700 inches **Overall Diameter:** 1.125 inches **Mounting Facility Quantity:** 1 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 3.00 amperes forward current, dc **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute Maximum Operating Tempurature Per Measurement Point: 150.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 case and 1 threaded stud Shelf Life: N/a Unit Of Measure: --**Demilitarization:** No Fiig: A110a0